Integrated silicon pressure sensor on-chip signal conditioned, temperature compensated and calibrated

Rev. 14 — 17 May 2024

Product data sheet

1 General description

The MPxx5010 series piezoresistive transducers are state-of-the-art monolithic silicon pressure sensors designed for a wide range of applications, but particularly those employing a microcontroller or microprocessor with A/D inputs. This transducer combines advanced micromachining techniques, thin-film metallization, and bipolar processing to provide an accurate, high level analog output signal that is proportional to the applied pressure. The axial port has been modified to accommodate industrial grade tubing.

2 Features and benefits

- 5.0% maximum error over 0° to 85° C
- · Ideally suited for microprocessor or microcontroller-based systems
- Durable epoxy unibody and thermoplastic (PPS) surface mount package
- Temperature compensated over -40° to +125° C
- · Patented silicon shear stress strain gauge
- · Available in differential and gauge configurations
- Available in surface mount (SMT) or through-hole (DIP) configurations

3 Applications

- Hospital beds
- HVAC
- Respiratory systems
- Process control
- Washing machine water level measurement (Reference AN1950)
- · Ideally suited for microprocessor or microcontroller-based systems
- · Appliance liquid level and pressure measurement



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4 Ordering information

Table 1.	Ordering	information
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Type number	Package								
	Name Description								
Unibody package (MPX5010 series)									
MPX5010DP	SENSOR4F	sensor package, 6 terminals, 2.54 mm pitch, 17.78 mm x 29.48 mm x 10.67 body	SOT1756-1						
MPX5010GP	SENSOR6F	sensor package, 6 terminals, 2.54 mm pitch, 17.78 mm x 29.47 mm x 8.01 mm body	SOT1852-1						
Small outline pack	age (MPXV50	10 series)	1						
MPXV5010DP	S08	plastic, small outline package, 8 terminals, 2.54 mm pitch, 12.06. mm x 12.06 mm x 7.62 mm body	SOT1693-1						
MPXV5010GC6T1	S08	plastic, small outline package, 8 terminals, 2.54 mm pitch, 10.67. mm x 10.67 mm x 12.96 mm body	SOT1854-1						
MPXV5010GC7U	S08	plastic, small outline package, 8 terminals, 2.54 mm pitch, 10.67. mm x 10.67 mm x 12.96 mm body	SOT1863-1						
MPXV5010GP	S08	plastic, small outline package, 8 terminals, 2.54 mm pitch, 12.06. mm x 12.06 mm x 7.62 mm body	SOT1693-3						
Small outline pack	age (Media re	esistant gel) (MPVZ5010 series)]						
MPVZ5010GW6U	S08	plastic, small outline package, 8 terminals, 2.54 mm pitch, 1.07 mm x 1.07 mm x 1.99 mm body	SOT1691-2						
MPVZ5010GW7U	S08	plastic, small outline package, 8 terminals, 2.54 mm pitch, 1.07 mm x 1.07 mm x 1.99 mm body	SOT1691-1						

4.1 Ordering options

 Table 2. Ordering options

ORDERING INFORMATION										
Device Name	Case No.		# of Ports	6		Pressure Type	e	Device		
Device Name	Case NO.	None	Single	Dual	Gauge	Differential	Absolute	Marking		
Unibody Package (I	Unibody Package (MPX5010 Series)									
MPX5010DP	867C			•		•		MPX5010DP		
MPX5010GP	867B		•		•			MPX5010GP		
Small Outline Packa	Small Outline Package (MPXV5010 Series)									
MPXV5010DP	1351			•		•		MPXV5010DP		
MPXV5010GC6T1	482A		•		•			MPXV5010G		
MPXV5010GC7U	482C		•		•			MPXV5010G		
MPXV5010GP	1369		•		•			MPXV5010GP		
Small Outline Package (Media Resistant Gel) (MPVZ5010 Series)										
MPVZ5010GW6U	1735		•		•			MZ5010GW		
MPVZ5010GW7U	1560		•		•			MZ5010GW		

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5 Block diagram



Figure 1 shows a block diagram of the internal circuitry integrated on a pressure sensor chip.

6 Pinning information

6.1 Pinning - Unibody packages





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6.2 Pin description - Unibody packages

Table 3. Pin descriptions - Unibody pacakages

This table defines the pin configuration for the Unibody packages indentified in Table 1.

Symbol	Pin	Description
V _{OUT}	1	V _{OUT}
GND	2	Ground
V _S	3	Supply voltage
N.C.	4	No connect
N.C.	5	No connect
N.C.	6	No connect

6.3 Pinning - Small Outline packages



Figure 4. MPXV5010DP - SOT1693-1 - Case 1351-01



Figure 5. MPXV5010GC6T1 - SOT1854-1 - Case 482A-01



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Figure 8. MPVZ5010GW6U - SOT1691-2 - Case 1735-01



Figure 9. MPVZ5010GW7U - SOT1691-1 - Case 1560-02

6.4 Pin description - Small Outline packages

Table 4. Pin descriptions - Small Outline packages

This table defines the pin configuration for the Small Outline packages indentified in <u>Table 1</u>.

Symbol	Pin	Description
N.C.	1	No connect
V _S	2	Supply voltage
GND	3	Ground
V _{OUT}	4	V _{OUT}
N.C.	5	No connect
N.C.	6	No connect
N.C.	7	No connect
N.C.	8	No connect

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7 Limiting values

Table 5. Limiting values^[1]

Rating	Symbol	Value	Unit
Maximum Pressure (P1 > P2)	P _{max}	40	kPa
Storage Temperature	T _{stg}	-40 to +125	°C
Operating Temperature	T _A	-40 to +125	°C

[1] Exposure beyond the specified limits may cause permanent damage or degradation to the device.

8 Recommended operating conditions

Table 6. Recommended operating conditions

 $V_{\rm S}$ = 5.0 Vdc, T_A = 25°C unless otherwise noted, P1 > P2. Decoupling circuit shown in <u>Figure 11</u> required to meet specification.)

Characteristic	Symbol	Min	Тур	Max	Unit
Pressure Range	P _{OP}	0		10	kPa
				1019.78	mm H ₂ O
Supply Voltage ^[1]	Vs	4.75	5.0	5.25	Vdc
Supply Current	Ι _ο	_	5.0	10	mAdc
Minimum Pressure Offset ^[2] (0 to 85°C)	V _{off}	0	0.2	0.425	Vdc
@ $V_{\rm S}$ = 5.0 Volts					
Full Scale Output ^[3] (0 to 85°C)	V _{FSO}	4.475	4.7	4.925	Vdc
@ V _S = 5.0 Volts					
Full Scale Span ^[4] (0 to 85°C)	V _{FSS}	4.275	4.5	4.725	Vdc
@ V _S = 5.0 Volts					
Accuracy ^[5] (0 to 85°C)	—	—	—	±5.0	%V _{FSS}
Sensitivity	V/P	—	450	—	mV/kPa
			4.413		mV/
					kpa H ₂ O
Response Time ^[6]	t _R		1.0		ms
Output Source Current at Full Scale Output	I _{O+}	—	0.1	-	mAdc
Warm-Up Time ^[7]	_		20		ms
Offset Stability ^[8]	-		±0.5	—	%V _{FSS}

[1] Device is ratiometric within this specified excitation range.

[2] Offset (V_{off}) is defined as the output voltage at the minimum rated pressure.

[3] Full Scale Output (V_{FSO}) is defined as the output voltage at the maximum or full rated pressure.

[4] Full Scale Span (V_{FSS}) is defined as the algebraic difference between the output voltage at full rated pressure and the output voltage at the minimum rated pressure.

[5] Accuracy (error budget) consists of the following:

Linearity: Output deviation from a straight line relationship with pressure over the specified pressure range.

Temperature Hysteresis: Output deviation at any temperature within the operating temperature range, after the temperature is cycled to and from the minimum or maximum operating temperature points, with zero differential pressure applied.

Pressure Hysteresis: Output deviation at any pressure within the specified range, when this pressure is cycled to and from the minimum or maximum rated pressure, at 25°C.

TcSpan: Output deviation over the temperature range of 0° to 85°C, relative to 25°C.

TcOffset: Output deviation with minimum rated pressure applied, over the temperature range of 0° to 85°C, relative to 25°C.

Variation from Nominal:The variation from nominal values, for Offset or Full Scale Span, as a percent of V_{FSS}, at 25°C.

MPX5010

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- [6] Response Time is defined as the time for the incremental change in the output to go from 10% to 90% of its final value when subjected to a specified step change in pressure.
- [7] Warm-up Time is defined as the time required for the product to meet the specified output voltage after the Pressure has been stabilized.
- [8] Offset Stability is the product's output deviation when subjected to 1000 hours of Pulsed Pressure, Temperature Cycling with Bias Test.

9 On-chip temperature compensation and calibration

The performance over temperature is achieved by integrating the shear-stress strain gauge, temperature compensation, calibration and signal conditioning circuitry onto a single monolithic chip.

<u>Figure 10</u> illustrates the differential or gauge configuration in the basic chip carrier (Case 482). A fluorosilicone gel isolates the die surface and wire bonds from the environment, while allowing the pressure signal to be transmitted to the sensor diaphragm.

The MPxx5010G series pressure sensor operating characteristics, and internal reliability and qualification tests are based on use of dry air as the pressure media. Media, other than dry air, may have adverse effects on sensor performance and long-term reliability. Contact the factory for information regarding media compatibility in your application.

<u>Figure 11</u> shows the recommended decoupling circuit for interfacing the integrated sensor to the A/D input of a microprocessor or microcontroller. Proper decoupling of the power supply is recommended.

<u>Figure 12</u> shows the sensor output signal relative to pressure input. Typical, minimum, and maximum output curves are shown for operation over a temperature range of 0° to 85°C using the decoupling circuit shown in <u>Figure 11</u>. The output will saturate outside of the specified pressure range.





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Nominal Transfer Value:

 $V_{OUT} = V_S \times (0.09 \times P + 0.04)$ $\pm (Pressure \ Error \times Temp. \ Factor \times 0.09 \quad V_S)$ $V_S = 5.0 \ V \ \pm 0.25 \ Vdc$



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10 Pressure (P1) / Vacuum (P2) side identification table

NXP designates the two sides of the pressure sensor as the Pressure (P1) side and the Vacuum (P2) side. The Pressure (P1) side is the side containing fluorosilicone gel which protects the die from harsh media. The MPX pressure sensor is designed to operate with positive differential pressure applied, P1 > P2.

The Pressure (P1) side may be identified by using Table 7.

Table 7. Pressure (P1) side identification

Part Number	Case Type	Pressure (P1) Side Identifier		
MPX5010DP	867C	Side with Part Marking		
MPX5010GP	867B	Side with Port Attached		
MPXV5010DP	1351	Side with Part Marking		
MPXV5010GC6T1	482A	Side with Port Attached		
MPXV5010GC7U	482C	Side with Port Attached		
MPXV5010GP	1369	Side with Port Attached		
MPVZ5010GW6U	1735	Vertical Port Attached		
MPVZ5010GW7U	1560	Vertical Port Attached		

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11 Minimum recommended footprint for surface mounted applications

Surface mount board layout is a critical portion of the total design. The footprint for the surface mount packages must be the correct size to ensure proper solder connection interface between the board and the package. With the correct footprint, the packages will self align when subjected to a solder reflow process. It is always recommended to design boards with a solder mask layer to avoid bridging and shorting between solder pads.



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12 Package outline



Figure 16. SOT1691-1 Package Outline



Figure 17. SOT1691-1 Package Outline Detail

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NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 1994.

2. CONTROLLING DIMENSION: INCH.

A DIMENSIONS DO NOT INCLUDE MOLD PROTRUSION.

4. MAXIMUM MOLD PROTRUSION IS .006.

- 5. ALL VERTICAL SURFACES 5' TYPICAL DRAFT.
- A DIMENSION TO CENTER OF LEAD WHEN FORMED PARALLEL.

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TITLE:		DOCUMEN	IT NO: 98ASA10611D	REV: E
SO, 8 I/O, .420 X .4		STANDAR	D: NON-JEDEC	
.100 IN PITCH	1	SOT1691-	-1	15 JAN 2016

Figure 18. SOT1691-1 Package Outline Notes



Figure 19. SOT1691-2 Package Outline

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Figure 20. SOT1691-2 Package Outline Detail

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NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 1994.

2. CONTROLLING DIMENSION: INCH.

 $\underline{\mathbb{R}}$ dimensions do not include mold protrusion.

4. MAXIMUM MOLD PROTRUSION IS .006.

5. ALL VERTICAL SURFACES 5' TYPICAL DRAFT.

6 DIMENSION TO CENTER OF LEAD WHEN FORMED PARALLEL.

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TITLE:		DOCUMEN	NT NO: 98ASA10686D	REV	': C
SO, 8 I/O, .420 X .4		STANDAF	D: NON-JEDEC		
.100 IN PITCH	4	SOT1691	-2	15 JAN 2	2016

Figure 21. SOT1691-2 Package Outline Notes



Figure 22. SOT1693-1 Package Outline

NOTES:

MPX5010-MPXV5010-MPVZ5010

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1. CONT	ROLLING	DIMENSION	I: INCH					
2. INTER	RPRET DI	MENSIONS	AND TOL	ERANCES P	ER ASME	Y14.5M-	-1994.	
	NSIONS D D FLASH	O NOT ING	CLUDE M TRUSIONS	OLD FLASH S SHALL NO	OR PPRO T EXCEED	TRUSION .006 PI	S. ER SIDE.	
		DES NOT IN SHALL BE			OTRUSION	. ALLOW	ABLE DAMBAR	
		STYI	PIN 3:	+Vout Vs -Vout N/C N/C N/C	STYL	E 2: PIN 1: PIN 2: PIN 3: PIN 4: PIN 5: PIN 6: PIN 7: PIN 8:	Vs GND Vout N/C N/C N/C	
© N	XP SEMICON ALL RIGHT	NDUCTORS N. V	/.	MECHAN	ICAL OU	TLINE	PRINT VERSION	NOT TO SCALE
TITLE:				I		DOCUME	INT NO: 98ASA9925	5D REV: 6
	8 LD	SNSR,	DUAL	PORT		STANDA	RD: NON-JEDEC	

Figure 23. SOT1693-1 Package Outline Notes



Figure 24. SOT1693-3 Package Outline

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NOTES: 1. CONTROLLING DIMENSION: INCH

- 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
- A DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PPROTRUSIONS. MOLD FLASH AND PROTRUSIONS SHALL NOT EXCEED .006 (0.152) PER SIDE.
- A DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .008 (0.203) MAXIMUM.

	INCHES MILLIMETERS			11	NCHES	MILL	METERS		
DIM	MIN	MAX	MIN	MAX	DIM	MIN	MAX	MIN	MAX
А	.300	.330	7.62	8.38	θ	0.	7.	0.	7.
A1	.002	.010	0.05	0.25	-				
Ь	.038	.042	0.96	1.07	-				
D	.465	.485	11.81	12.32	-				
E	.717	BSC	18	.21 BSC	-				
E1	.465	.485	11.81	12.32	-				
е	.100	BSC	2.	54 BSC	-				
F	.245	.255	6.22	6.47	-				
к	.120	.130	3.05	3.30	-				
L	.061	.071	1.55	1.80	-				
М	.270	.290	6.86	7.36	-				
Ν	.080	.090	2.03	2.28	-				
Р	.009	.011	0.23	0.28	-				
Т	.115	.125	2.92	3.17	-				
	© NXP SEMICO ALL RIGH	ONDUCTORS N. V		MECHANICA	L OU	L TLINE	PRINT VER	I SION NOT	TO SCALE
ΤΙΤΙ	_E:					DOCUME	NT NO: 98ASA	99303D	REV: E
	8 LC) SOP, S	IDE PO	DRT		STANDAR	RD: NON-JEDE	С	
		,				S0T1693	3–3	14	MAR 2016

Figure 25. SOT1693-3 Package Outline Notes



Figure 26. SOT1756-1 Package Outline



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NOTES:				
1. DIMENSIONS ARE IN MILLIMETER	S.			
2. DIMENSIONS AND TOLERANCES	PER ASME Y14.5M-	1994.		
3. 867B-01 THRU -3 OBSOLETE,	NEW STANDARD 86	7B-04.		
STYLE 1:				
PIN 1: V OUT 2: GROUND				
3: VCC 4: V1				
5: V2 6: V EX				
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ALL RIGHTS RESERVED			T NO: 98ASB42796B	REV: J
SENSOR, 6 LEAD UNIBO	DY CELL,		: NON-JEDEC	
AP & GP 01ASB09		SOT1852-		5 MAR 2016



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NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1982.
- 2. CONTROLLING DIMENSION: INCH.
- 3. DIMENSION 'A' AND 'B' DO NOT INCLUDE MOLD PROTUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006).
- 5. ALL VERTICAL SURFACES 5' TYPICAL DRAFT.

	INCH	IES	MILL	IMETERS				
DIM	MIN	MAX	MIN	MAX				
A	0.415	0.425	10. 54	4 10.79				
В	0.415	0.425	10. 54	10.79				
С	0.500	0.520	12.70	13.21				
D	0.038	0.042	0.96	6 1.07				
G	0.100	BSC	2.5	54 BSC				
н	0.002	0.010	0. 05	0.25				
J	0.009	0.011	0. 23	0.28				
K	0.061	0.071	1. 55	1.80				
м	0°	7°	0°	7°				
N	0.444	0.448	11.28	3 11.38				
S	0.709	0. 725	18.01	1 18.41				
V	0.245	0. 255	6. 22	6.48				
W	0.115	0.125	2. 92	3.17				
0	NXP SEMICOND		<u> </u>					
	ALL RIGHTS			MECHANICA	L OUT	「LINE	PRINT VERSION N	OT TO SCALE
TITLE:	SENSOR UNIBODY			ODY, DOCUMENT NO: 98ASB17757C REV:			REV: C	
	11.33 X				Γ	STANDAF	RD: NON-JEDEC	
	2.5	54 PITCI	PITCH, 8 I/O			SOT1854–1 13 JUL 2017		

Figure 30. SOT1854-1 Package Outline Notes



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NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1982.
- 2. CONTROLLING DIMENSION: INCH.
- 3. DIMENSION 'A' AND 'B' DO NOT INCLUDE MOLD PROTUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006).
- 5. ALL VERTICAL SURFACES 5' TYPICAL DRAFT.
- 6. DIMENSION 'S' TO CENTER OF LEAD WHEN FORMED PARALLEL.
- 7. 482C-01 AND -02 OBSOLETE. NEW STANDARD 482C-03.

	MILLIN	IETERS	INC	HES				
DIM	MIN	MAX	MIN	MAX				
A	10. 54	10.79	0.415	0. 425				
В	10.54	10.79	0.415	0.425				
С	12. 70	13.21	0. 500	0.520				
D	0.66	0.864	0. 026	0.034				
G	2.54	BSC	0. 100	BSC				
J	0. 23	0.28	0. 009	0.011				
К	2.54	3.05	0. 100	0.120				
М	0°	15°	0°	15°				
Ν	11.28	11.38	0. 444	0.448				
S	13. 72	14.22	0. 540	0.560				
V	6. 22	6.48	0. 245	0.255				
W	2. 92	3.17	0.115	0.125				
							1	
©	NXP SEMICO ALL RIGH	NDUCTORS N.V TS RESERVED		MECHANICA	LOU	TLINE	PRINT VERSION NO	DT TO SCALE
TITLE:		SENSOR	UNIBOD	INIBODY. DOCUMENT NO: 98ASB17759C		REV: F		
				55 PKG,		STANDAF	RD: NON-JEDEC	
	2	2.54 PIT	CH, 8 I	/0		SOT1863-1 24 OCT 201		

Figure 32. SOT1863-1 Package Outline Notes

Integrated silicon pressure sensor on-chip signal conditioned, temperature compensated and calibrated

13 Revision history

Table 8. Revisio	on history	
Document ID	Release date	Description
MPX5010 v.14	17 May 2024	• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate.
		 <u>Section 4, Table 1</u> and <u>Section 4.1 Table 2</u>, removed devices MPX5010GS, MPX5010GSX, MPXV5010G6U, MPXV5010GC6U, MPVZ5010G7U, and MPVZ5010 G6U. <u>Section 8, Table 6</u>, Sensitivity Unit: Revised "mV/mm" to "mV/kPa".
MPX5010 v.13	October 2012	 Deleted references to device number MPVZ5010G6T1, MPVZ5010G6U/T1 and MPVZ5010G6U/6T1 throughout the document.

Integrated silicon pressure sensor on-chip signal conditioned, temperature compensated and calibrated

Legal information

Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>https://www.nxp.com</u>.

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MPX5010 Product data sheet

NXP Semiconductors

MPX5010-MPXV5010-MPVZ5010

Integrated silicon pressure sensor on-chip signal conditioned, temperature compensated and calibrated

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